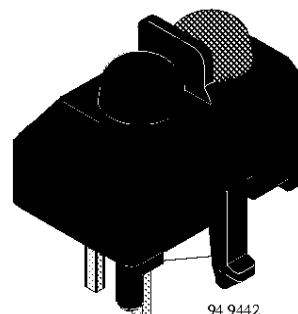


## Reflective Optosensor with Transistor Output

### Description

The TCRT5000(L) has a compact construction where the emitting-light source and the detector are arranged in the same direction to sense the presence of an object by using the reflective IR beam from the object.

The operating wavelength is 950 nm. The detector consists of a phototransistor.



### Applications

- Position sensor for shaft encoder
- Detection of reflective material such as paper, IBM cards, magnetic tapes etc.
- Limit switch for mechanical motions in VCR
- General purpose – wherever space is limited

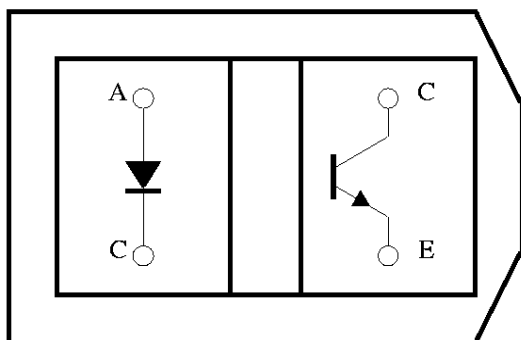
### Features

- Snap-in construction for PCB mounting
- Package height: 7 mm
- Plastic polycarbonate housing construction which prevents crosstalk
- L = long leads

### Order Instruction

Part Numbers	Remarks
TCRT5000	Leads (3.5 mm)
TCRT5000L	Long leads (15 mm)

### Pin Connection



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## Absolute Maximum Ratings

### Input (Emitter)

Parameters	Test Conditions	Symbol	Value	Unit
Reverse voltage		$V_R$	5	V
Forward current		$I_F$	60	mA
Forward surge current	$t_p \leq 10 \mu A$	$I_{FSM}$	3	A
Power dissipation	$T_{amb} \leq 25^\circ C$	$P_v$	100	mW
Junction temperature		$T_j$	100	$^\circ C$

### Output (Detector)

Parameters	Test Conditions	Symbol	Value	Unit
Collector emitter voltage		$V_{CEO}$	70	V
Emitter collector voltage		$V_{ECO}$	5	V
Collector current		$I_C$	100	mA
Power dissipation	$T_{amb} \leq 55^\circ C$	$P_v$	100	mW
Junction temperature		$T_j$	100	$^\circ C$

### Sensor

Parameters	Test Conditions	Symbol	Value	Unit
Total power dissipation	$T_{amb} \leq 25^\circ C$	$P_{tot}$	200	mW
Operation temperature range		$T_{amb}$	-25 to +85	$^\circ C$
Storage temperature range		$T_{sig}$	-25 to +100	$^\circ C$
Soldering temperature	2 mm from case, $t \leq 10$ s	$T_{sd}$	260	$^\circ C$

## Electrical Characteristics

### Input (Emitter)

Parameters	Test Conditions / Pins	Symbol	Min.	Typ.	Max.	Unit
Forward voltage	$I_F = 60 \text{ mA}$	$V_F$		1.25	1.5	V
Junction capacitance	$V_R = 0 \text{ V}, f = 1 \text{ MHz}$	$C_j$		50		pf

### Output (Detector)

Parameters	Test Conditions / Pins	Symbol	Min.	Typ.	Max.	Unit
Collector emitter voltage	$I_C = 1 \text{ mA}$	$V_{CEO}$	70			V
Emitter collector voltage	$I_E = 100 \mu\text{A}$	$V_{ECO}$	7			V
Collector dark current	$V_{CE} = 20 \text{ V}, I_F = 0, E = 0$	$I_{CEO}$		10	200	nA

### Sensor

Parameters	Test Conditions / Pins	Symbol	Min.	Typ.	Max.	Unit
Collector current	$V_{CE} = 5 \text{ V}, I_F = 10 \text{ mA}$ $D = 12 \text{ mm}$	$I_C^{1,2)}$	0.5	1	1.6	mA
Collector emitter saturation voltage	$I_F = 10 \text{ mA}, I_C = 0.1 \text{ mA},$ $D = 12 \text{ mm}$	$V_{CEsat}^{1,2)}$			0.4	V

- 1) See test circuit  
2) Test surface: Mirror (Mfr. Spindler & Hoyer, Part No 340005)

### Test Circuit

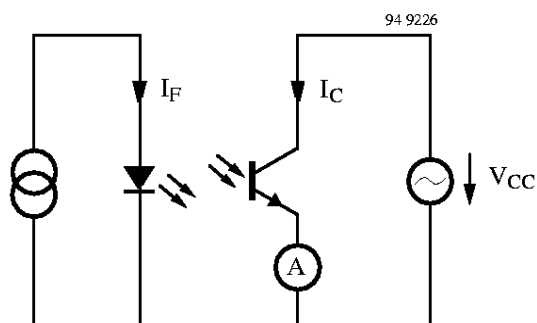


Figure 1.

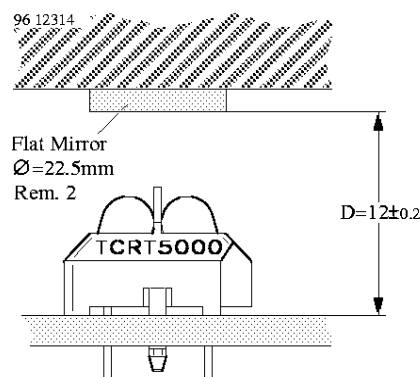


Figure 2.

## Typical Characteristics ( $T_{amb} = 25^{\circ}\text{C}$ , unless otherwise specified)

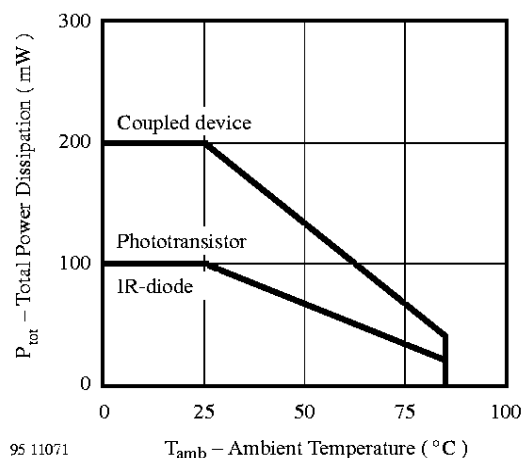


Figure 3. Total Power Dissipation vs. Ambient Temperature

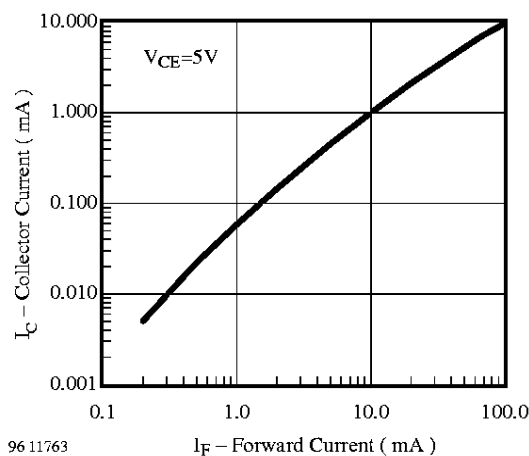


Figure 6. Collector Current vs. Forward Current

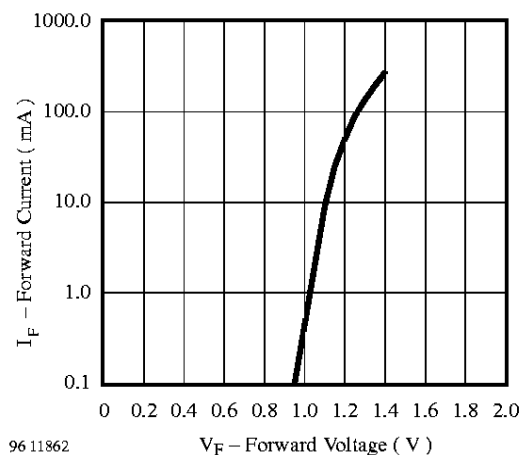


Figure 4. Forward Current vs. Forward Voltage

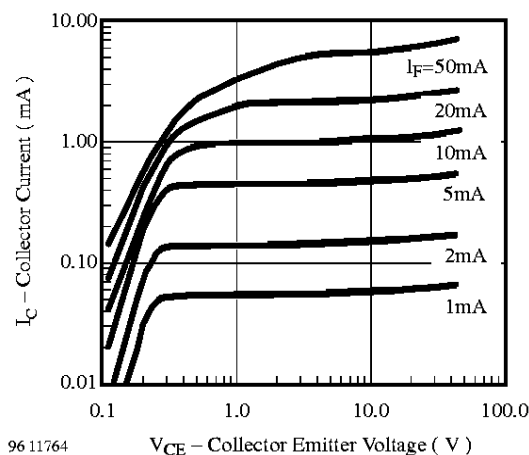


Figure 7. Collector Emitter Sat. Voltage vs. Collector Current

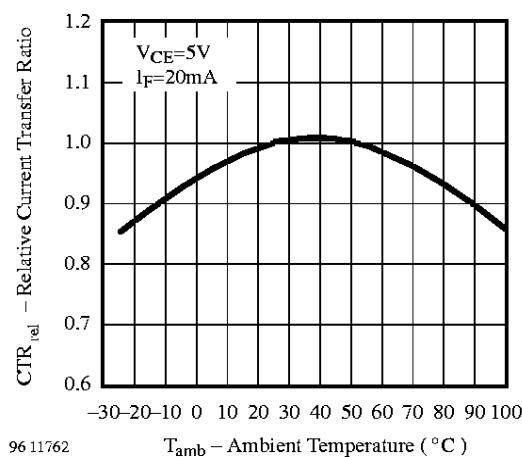


Figure 5. Rel. Current Transfer Ratio vs. Ambient Temperature

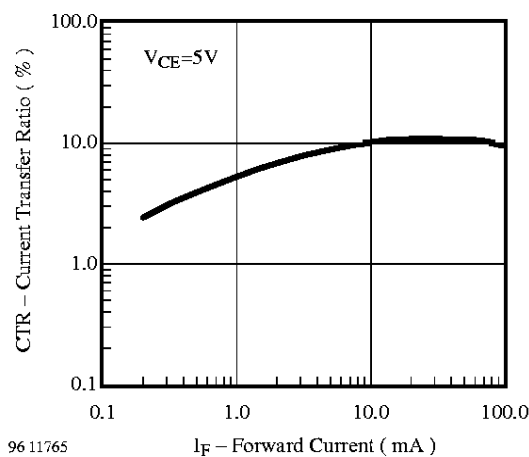


Figure 8. Current Transfer Ratio vs. Forward Current

**Typical Characteristics** ( $T_{amb} = 25^{\circ}C$ , unless otherwise specified)

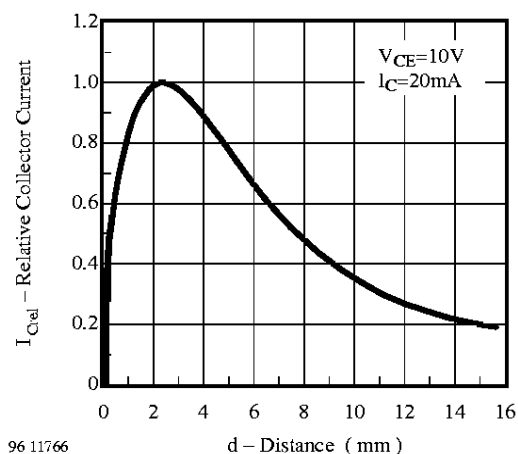


Figure 9. Relative Collector Current vs. Distance

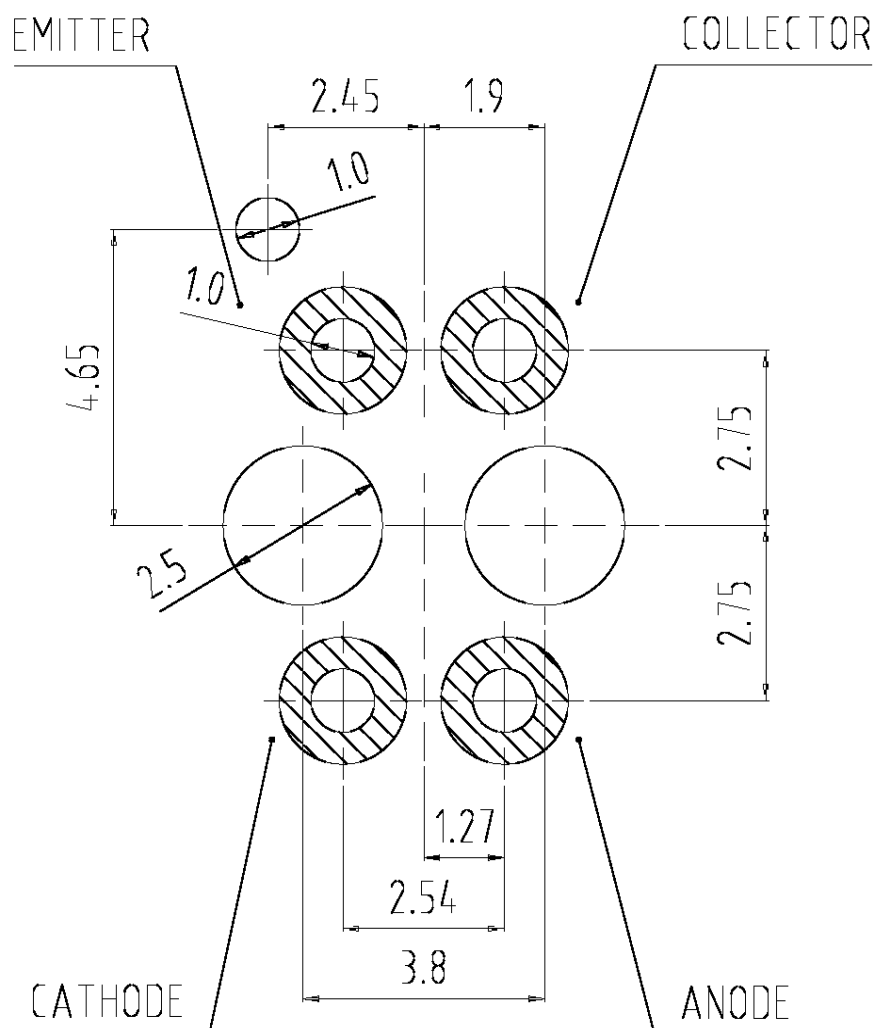
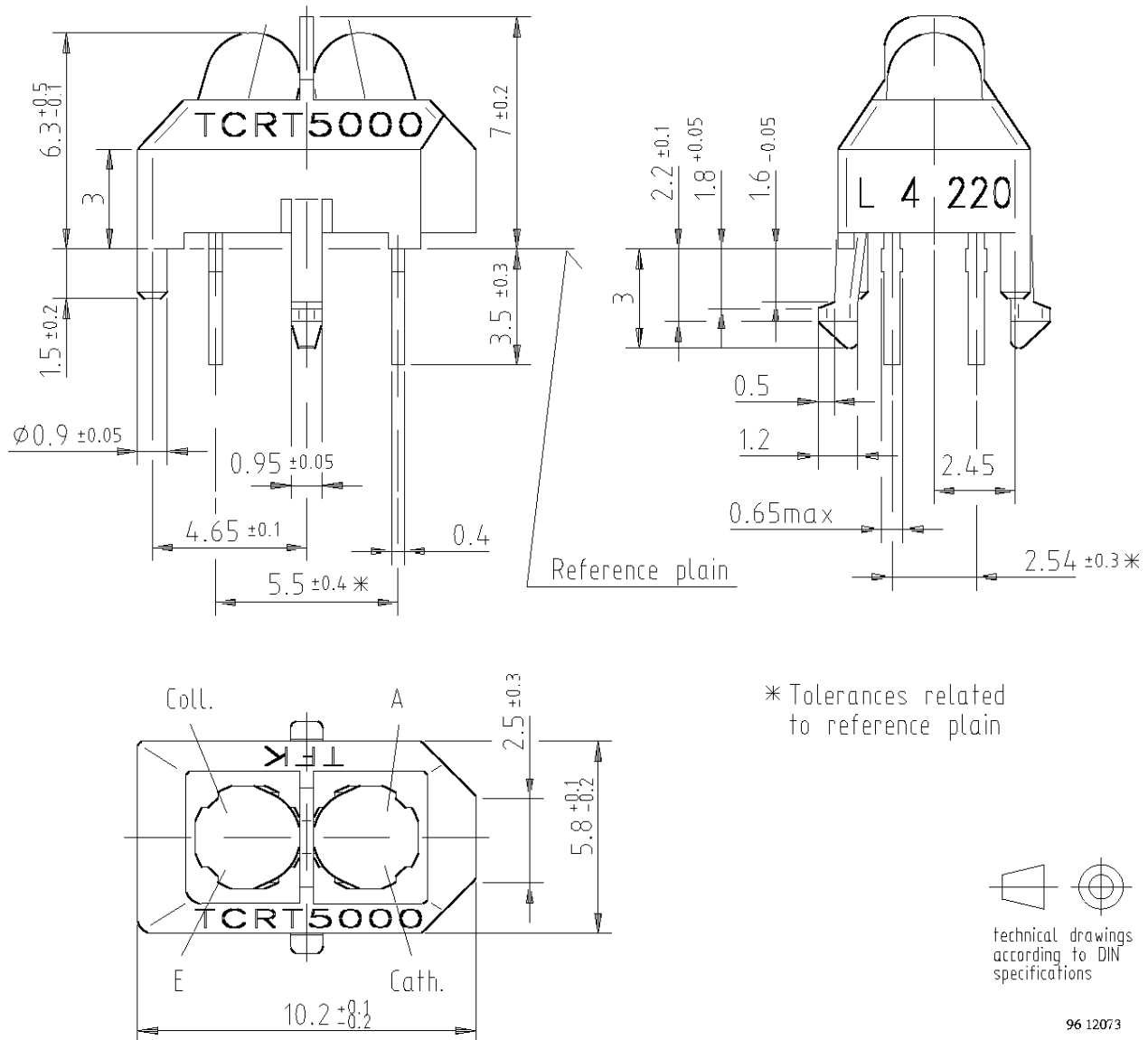


Figure 10. Footprint

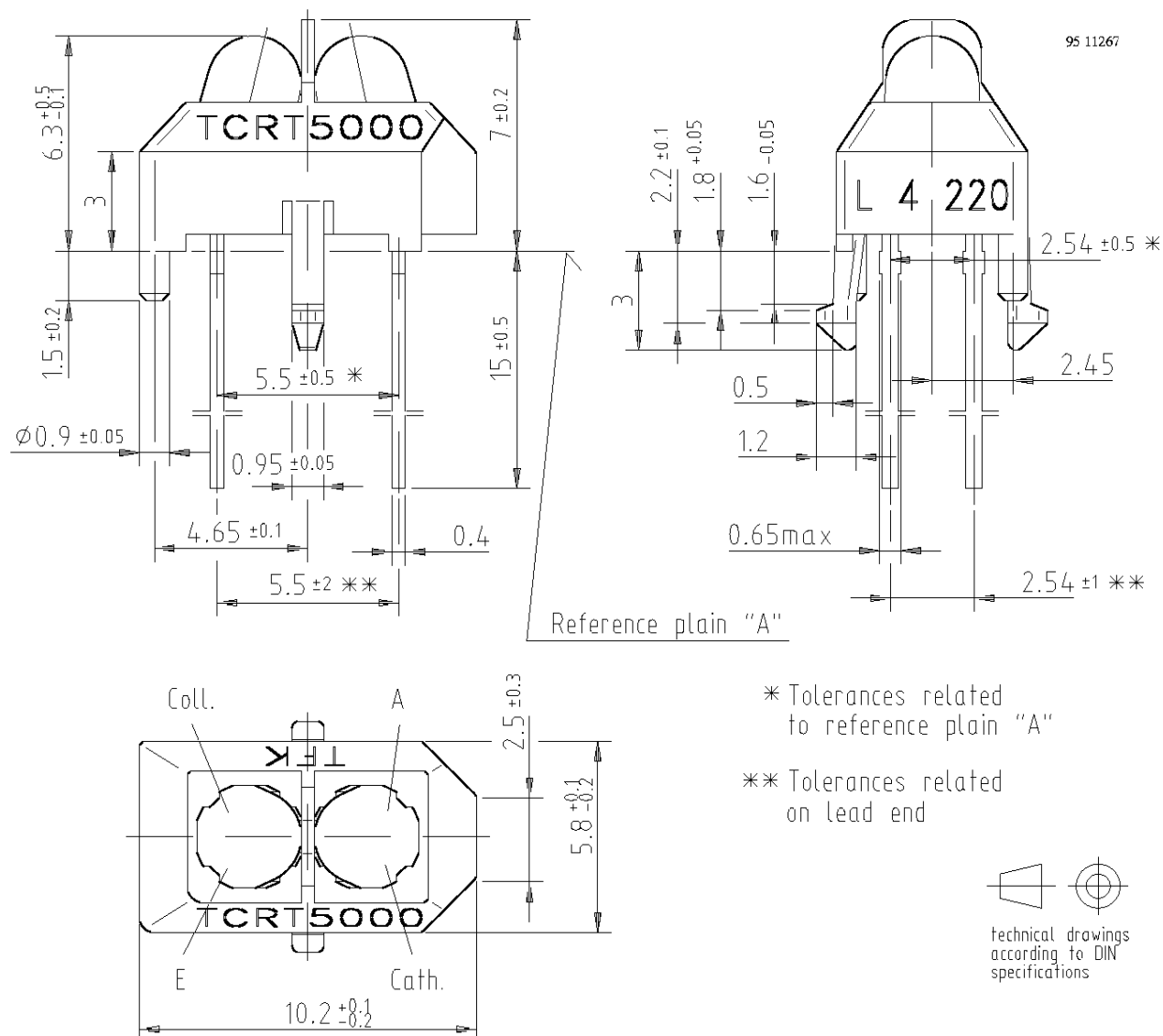
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## Dimensions of TCRT5000 in mm



weight: 0.23 g

## Dimensions of TCRT5000L in mm



weight: ca. 0.23 g

## Ozone Depleting Substances Policy Statement

It is the policy of **TEMIC TELEFUNKEN microelectronic GmbH** to

1. Meet all present and future national and international statutory requirements.
2. Regularly and continuously improve the performance of our products, processes, distribution and operating systems with respect to their impact on the health and safety of our employees and the public, as well as their impact on the environment.

It is particular concern to control or eliminate releases of those substances into the atmosphere which are known as ozone depleting substances (ODSs).

The Montreal Protocol (1987) and its London Amendments (1990) intend to severely restrict the use of ODSs and forbid their use within the next ten years. Various national and international initiatives are pressing for an earlier ban on these substances.

**TEMIC TELEFUNKEN microelectronic GmbH** semiconductor division has been able to use its policy of continuous improvements to eliminate the use of ODSs listed in the following documents.

1. Annex A, B and list of transitional substances of the Montreal Protocol and the London Amendments respectively
2. Class I and II ozone depleting substances in the Clean Air Act Amendments of 1990 by the Environmental Protection Agency (EPA) in the USA
3. Council Decision 88/540/EEC and 91/690/EEC Annex A, B and C (transitional substances) respectively.

**TEMIC** can certify that our semiconductors are not manufactured with ozone depleting substances and do not contain such substances.

**We reserve the right to make changes to improve technical design and may do so without further notice.**

Parameters can vary in different applications. All operating parameters must be validated for each customer application by the customer. Should the buyer use TEMIC products for any unintended or unauthorized application, the buyer shall indemnify TEMIC against all claims, costs, damages, and expenses, arising out of, directly or indirectly, any claim of personal damage, injury or death associated with such unintended or unauthorized use.

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